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# Raman studies on solid CH<sub>4</sub> at room temperature to 208 GPa

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#### Abstract

Solid methane has been studied by Raman scattering under high pressure in a diamond anvil cell at room temperature. Internal modes  $v_1$  and  $v_3$  have been followed up to 208 GPa. The results indicated that methane remained in molecular form and kept its high-pressure phase structure to the highest pressure investigated. Fitting x-ray diffraction data from the literature by the Vinet equation of state from 16.9 to 37 GPa gives values of  $K_0 = 6.4 \pm 0.73$  GPa,  $K'_0 = 5.68 \pm 0.36$  and  $V_0 = 25.44$  cm<sup>3</sup> mol<sup>-1</sup>. Extrapolation of the above equation of state showed that the volume of methane changes from 11.84 to 6.63 cm<sup>3</sup> mol<sup>-1</sup> as pressure increases from 34 to 208 GPa. Furthermore, the metallization pressure of solid CH<sub>4</sub> has been roughly estimated on the basis of our recent results and extrapolated equation of state.

## 1. Introduction

The simplest hydrocarbon, methane, is a gas at room temperature and ambient pressure with a chemical formula of  $CH_4$ . Theoretical calculations by Ashcroft implied that  $CH_4$  will become metallic at available pressures and may be a high- $T_c$  superconductor [1]. The superconductivity of Li [2] and MgB<sub>2</sub> [3] also suggested that a number of compounds of low atomic number elements [4] may be metallized at high pressure. Therefore, study of metallization of solid

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CH<sub>4</sub> under high pressure is of importance from physical, chemical and technological points of view.

Earlier studies have shown that there were four solid phases of methane discovered using optical and x-ray diffraction measurements at room temperature and pressures of 1.6–37 GPa [5–9]. Phase I has an fcc structure above 1.6 GPa with one molecule in the primitive cell [8]. Phase A has a rhombohedral structure at pressures of 5.3-9 GPa with 21 molecules in a unit cell [9] and its structure is similar to the structure of phase I of CF<sub>4</sub> [10]. X-ray diffraction measurements by Umemoto *et al* [11] indicated that phase B has cubic structure below 16.9 GPa. At pressures above 16.9 GPa, phase B transforms to the cubic high-pressure phase (HP phase), and the HP phase persists to 37 GPa. However, there is less detailed knowledge about the phase transition or phase stability for solid CH<sub>4</sub> at multimegabars. In this paper, we used symmetry modes of Raman scattering as a probe to study the high-pressure behavior of solid CH<sub>4</sub>.

#### 2. Experiment

We used a diamond anvil cell (DAC) to create high pressure. Diamonds selected carefully for Raman spectroscopy research with very low birefringence were used for x-ray diffraction and Raman measurements. The tips of the diamonds used for this study were 35  $\mu$ m with a single level. The high-purity CH<sub>4</sub> 99.99% gas was loaded into the tungsten gasket hole of the DAC at room temperature, and then the sample was clamped and further pressurized by closing two diamonds mechanically via a gear box. The initial sample size was 17  $\mu$ m in diameter and 8.0  $\mu$ m in thickness for the first experiment and 17  $\mu$ m in diameter and 8.5  $\mu$ m in thickness for the second experiment (the thickness of the sample was determined by interference pattern measurements [12, 13]).

To achieve accurate pressure measurements, a submicron layer of platinum (Pt) was deposited onto the side wall of the gasket hole as a pressure marker [14]. A collimated x-ray beam of  $15 \times 25 \ \mu$ m was used to study the volume changes of the Pt deposited on the side wall of the gasket hole. Pressure was determined against the Pt isotherm equation of state [15]. The Raman measurements were carried out at room temperature to 208 GPa using a micro-optical system equipped with a microscope and fiber optics connecting to a spectrometer [16]. The experimental data for separate experiments were recorded by a CCD detector.

## 3. Results and discussion

Solid CH<sub>4</sub> has three internal modes,  $v_1$ ,  $v_2$  and  $v_3$  with frequency ( $\sigma$ ) at  $\sigma_1 = 2914.2 \text{ cm}^{-1}$ ,  $\sigma_2 = 1526 \text{ cm}^{-1}$  and  $\sigma_3 = 3022 \text{ cm}^{-1}$  at zero pressure [7]. In this study, attention was focused on mode  $v_1$  and  $v_3$ . Figure 1 shows Raman spectra of solid CH<sub>4</sub> at different pressures. The frequencies of  $v_1$  and  $v_3$  shift to the high-wavenumber side as pressure increases. The pressure dependence of the Raman frequencies of CH<sub>4</sub> for two experiments is summarized in figure 2. At pressure below 12 GPa, the wavenumber of mode  $v_1$  and  $v_3$  as a function of pressure has a small difference on the slope due to the fact that CH<sub>4</sub> undergoes several phase transitions [7]. We found that the frequencies of  $v_1$  and  $v_3$  increased linearly with pressure in the pressure range of 34–208 GPa, which may suggest that there is no phase transition in solid CH<sub>4</sub>; in other words, solid CH<sub>4</sub> may retain HP phase structure to 208 GPa. Curve fitting yields

$$\sigma_1(\text{cm}^{-1}) = 3154.5(\pm 4.22) + 1.11(\pm 0.03)P \text{ (GPa)}$$
(1)

$$\sigma_3(\text{cm}^{-1}) = 3268.7(\pm 6.76) + 1.94(\pm 0.05)P \text{ (GPa)}.$$
(2)

2



Figure 1. Solid  $CH_4$  Raman spectra at high pressures.



Figure 2. Raman frequencies of solid CH<sub>4</sub> as a function of pressure to 208 GPa. The open squares and circles represent mode  $\nu_1$  and mode  $\nu_3$  for two separate experiments and the open diamonds and triangles are data points of [7].

(This figure is in colour only in the electronic version)

The P(V) isotherm for the HP phase of CH<sub>4</sub> has been studied by synchrotron x-ray diffraction from 16.9 to 37 GPa [11]. Inasmuch as the Vinet equation gives an excellent fit for the molecular solid H<sub>2</sub> to high pressure [17], it was used to fit the data of [11]. The Vinet



Figure 3. The volume of solid  $CH_4$  as a function of pressure. Solid squares are data points obtained from [11] and the line is our fit using the Vinet equation of state.

equation is given by [18]

$$P = 3K_0 \left(\frac{V}{V_0}\right)^{-\frac{2}{3}} \left[1 - \left(\frac{V}{V_0}\right)^{\frac{1}{3}}\right] \exp\left\{\frac{3}{2}(K'_0 - 1)\left[1 - \left(\frac{V}{V_0}\right)^{\frac{1}{3}}\right]\right\}$$
(3)

where  $K_0$  is the bulk modulus at room pressure,  $K'_0$  is the first derivative of the bulk modulus at zero pressure and  $V_0$  is the volume in the Vinet equation of state at zero pressure. This results in values of  $K_0 = 6.4 \pm 0.73$  GPa,  $K'_0 = 5.68 \pm 0.36$  and  $V_0 = 25.44$  cm<sup>3</sup> mol<sup>-1</sup>. Figure 3 shows the volume of CH<sub>4</sub> as a function of pressure. It should be noted that the volume of CH<sub>4</sub> changes from 11.84 to 6.63 cm<sup>3</sup> mol<sup>-1</sup> as pressure increases from 34 to 208 GPa.

In earlier studies, the Goldhammer–Herzfeld (GH) equation has been used as a simple criterion for insulator–metal transition of materials such as gases and alkali hydrides. From the Lorentz–Lorenz equation

$$\frac{n^2 - 1}{n^2 + 2} = \frac{R}{V}.$$
(4)

Goldhammer and later Herzfeld assumed *R* did not change with *V* (or *P*) and noted that when  $n \to \infty$ 

$$\frac{R}{V} = 1.$$
(5)

Metallization occurs when V decreases to R. Here n is the refractive index, R is the molar refraction and V is the molar volume. According to the GH criterion, metallization for BaTe [19] and xenon [20] occurs at V = R. The molar refraction of methane at low pressure is R = 6.54 cm<sup>3</sup> mol<sup>-1</sup> [21]. From the extrapolated equation of state (EOS) the metallization pressure of solid CH<sub>4</sub> is 220 GPa, for which the volume, V, is equal to R.

Recently our reflectivity and absorption measurements to 288 GPa [22] indicated that the molar refraction (R) of solid CH<sub>4</sub> is not constant with pressure. The value of R/V increased linearly as pressure increased. A significant jump in refractive index, absorption coefficient and R/V at 288 GPa suggested that solid CH<sub>4</sub> has changed to a semiconductor at this pressure and room temperature (the R/V value at 288 GPa is very close to the R/V value of silicon).

On the basis of the extrapolated EOS, it is noted that the 11.3% volume change has been observed as pressure increases from 208 to 288 GPa. If the volume at 288 GPa is reduced to

5.88 cm<sup>3</sup> mol<sup>-1</sup> by increased pressure and this is followed by a phase transition with a 20.9% volume decrease (as occurs in silicon from the diamond cubic to the  $\beta$ -Sn structure [23, 24]) to 4.65 cm<sup>3</sup> mol<sup>-1</sup>, i.e. to *R*, a rough estimation of the metallization pressure of solid CH<sub>4</sub> would be about ~520 GPa at room temperature.

## 4. Conclusion

High-pressure Raman spectra of solid methane have been studied to 208 GPa at room temperature. We found that the symmetry modes  $v_1$  and  $v_3$  increased linearly as pressure increased from 34 to 208 GPa. Based on x-ray diffraction measurements for the HP phase of solid methane [11], the data points from 16.9 to 37 GPa were fitted using the Vinet equation of state and extrapolated to 208 GPa, which gives  $K_0 = 6.4 \pm 0.73$  GPa,  $K'_0 = 5.68 \pm 0.36$  and  $V_0 = 25.44$  cm<sup>3</sup> mol<sup>-1</sup>. Taking a first phase transition into account at 288 GPa [22], the metallization pressure of solid CH<sub>4</sub> at room temperature has been estimated to be about 520 GPa.

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